

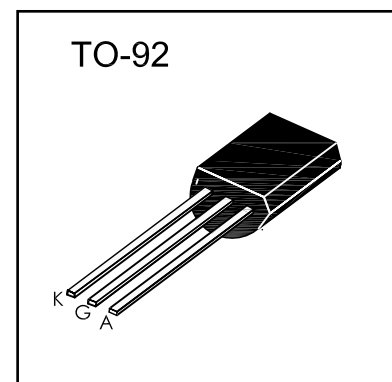
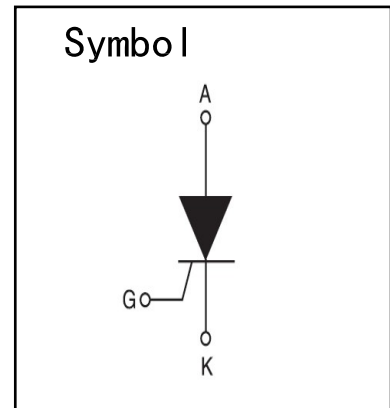
0.8A SCRs

FEATURES

- ◆ Repetitive Peak Off-State Voltage : 400V
- ◆ Average On-State Current ($I_{T(AV)} = 0.8 \text{ A}$)
- ◆ Sensitive Gate Triggering ($I_{GT} \leq 200\mu\text{A}$)

DESCRIPTION

Highly sensitive triggering levels, the BPL1225 Series SCRs is suitable for all applications, where the available gate current is limited, such as capacitive discharge ignitions, motor control in kitchen aids, overvoltage crowbar protection in low power supplies...



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit	
Storage junction temperature range	Tstg	- 40 to +150	°C	
Operating junction temperature range	Tj	- 40 to +110	°C	
Repetitive Peak Off-state Voltage	Tj=25°C	VDRM	400	V
Repetitive Peak Reverse Voltage	Tj=25°C	VRRM	400	V
RMS on-state current (180° conduction angle)	Tc=77°C	IT(RMS)	0.8	A
Average on-state current (180° conduction angle)	Tc=77°C	IT(AV)	0.8	A
Non repetitive surge peak on-state current (Tj=25°C)	tp=10ms	ITSM	9	A
	tp=8.3ms		10	A
I²t Value for fusing	tp=10ms	I²t	0.415	A²s
Peak gate current	tp=20us, Tj=110°C	IGM	0.2	A
Average gate power dissipation	Tj=110°C	PG(AV)	0.1	W

ELECTRICAL CHARACTERISTICS($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition		BPL1225			Unit	
			Min.	Typ.	Max.		
I _{GT}	V _D =6V R _L =100Ω		-	40	200	μA	
V _{GT}			-	0.6	0.8	V	
V _{GD}	V _D =V _{DRM} R _L =3.3KΩ R _{GK} =1KΩ T _j =110°C		0.2	-	-	V	
I _L	I _G =1mA R _{GK} =1KΩ		-	-	6	mA	
I _H	I _T =50mA R _{GK} =1KΩ		-	-	5	mA	
V _{TM}	I _T = 1A t _p =380uS	T _j =25 °C	-	1.3	1.7	V	
dV/dt	V _D =67%V _{DRM} R _{GK} =1KΩ	T _j =110 °C	10	-	-	V/μs	
I _{DRM}	V _D = V _{DRM} R _{GK} =1KΩ		T _j =25 °C	-	-	5	μA
			T _j =110 °C	-	-	0.1	mA
I _{RRM}	V _R = V _{RRM} R _{GK} =1KΩ		T _j =25 °C	-	-	5	μA
			T _j =110 °C	-	-	0.1	mA

FIG.1: Maximum power dissipation versus RMS on-state current(full cycle)

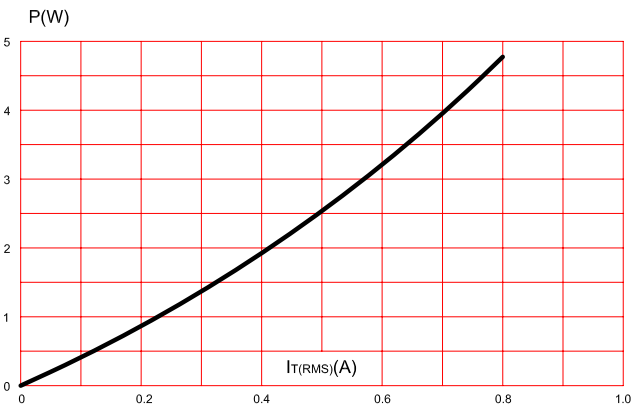


FIG.2: RMS on-state current versus case temperature(full cycle)

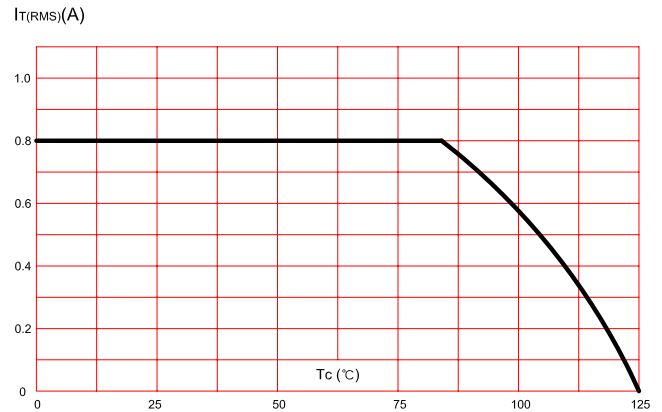


FIG.3: On-state characteristics (maximum values)

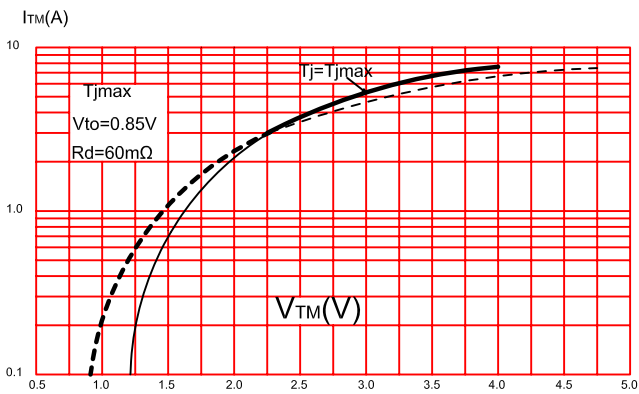


FIG.4: Surge peak on-state current versus number of cycles.

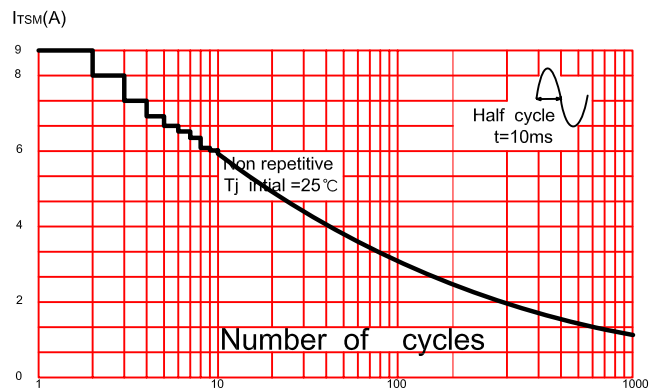


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10ms$.

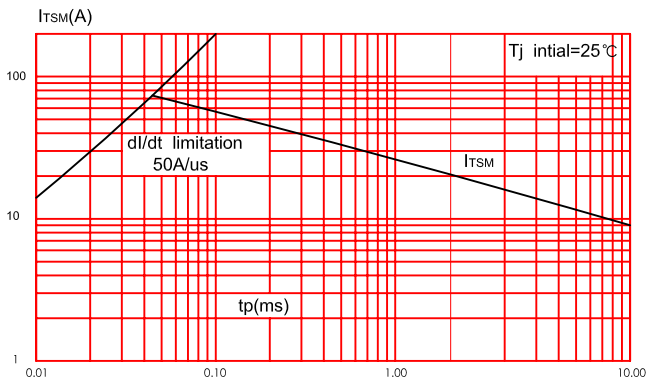
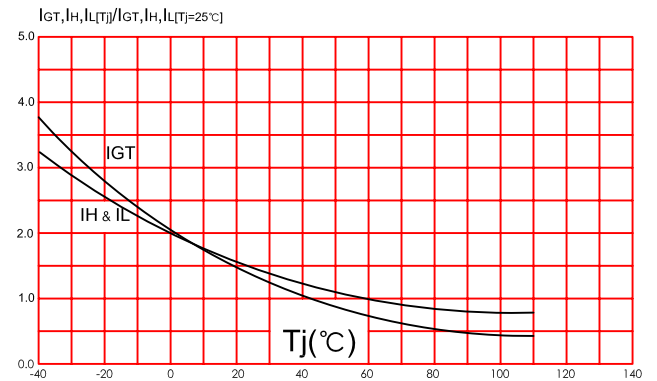
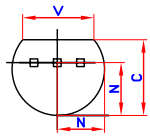


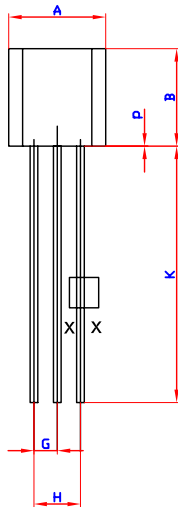
FIG.6: Relative variation of gate trigger current, holding current and latching current versus junction temperature(typical values).



TO-92 Package Dimension



SECTION X-X



TO-92(TO-226AA)

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.45	5.2	0.175	0.205
B	4.32	5.33	0.170	0.210
C	3.18	4.19	0.125	0.165
D	0.407	0.533	0.016	0.021
G	1.15	1.39	0.045	0.055
H	2.42	2.66	0.095	0.105
J	0.39	0.50	0.015	0.020
K	12.70	-	0.500	-
N	2.04	2.66	0.080	0.105
P	-	2.54	-	0.100
V	3.43	-	0.135	-